

A Low Power VLSI Implementation of STTRAM based TCAM for High Speed Switching Circuits

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ABSTRACT

Ternary content-addressable memory (TCAM) is often used in high speed search intensive applications such as ATM switch, IP filters. Hence, currently ZTCAM, is introduced which emulates the TCAM functionality with SRAM. It has some drawbacks such as low scalability, low storage density, slow access time and high cost. But this paper proposes novel memory architecture of existing Z-TCAM, but with STTRAM instead of SRAM. Hence the area, delay and power by using lower power consumption Spin Transfer Torque RAM (STT RAM) instead of SRAM. The detailed implementation results and power measurements for each design have been reported thoroughly.

General Terms

Memory Search, Low power, VLSI.

Keywords

Ternary Content Addressable Memory, Spin Transfer Torque RAM, Hybrid Partitioning.

1. INTRODUCTION

CAM stands for **Content Addressable Memory** which is a special type of memory used by Cisco switches. In the case of ordinary RAM the IOS uses a memory address to get the data stored at this memory location, while with CAM the IOS does the inverse. It uses the data and the CAM returns the address where the data is stored. Also the CAM is considered to be faster than the RAM since the CAM searches the entire memory in one operation. CAM tables provide only two results: 0 (true) or 1 (false).[8]

TCAM stands for **Ternary Content Addressable Memory** is the capability extension of CAM which can match a third state, which is any value. This makes TCAM a very important component of Cisco Layer 3 switches and modern routers, since they can store their routing table in the TCAMs, allowing for very fast lookups, which is considerably better than routing tables stored in ordinary RAM. TCAM is a specialized CAM designed for rapid table lookups [8]. TCAM A cell has two static random access memory (SRAM) cells and a comparison circuitry and provides three state: 0, 1, and x where x is a don't care state. The x state is always regarded as matched irrespective of the input bit. TCAM provides single clock lookup with constant search time which makes it suitable for applications such as network routers, data compression, real-time pattern matching in virus-detection, and image processing.

In paper [1] TCAM is designed using SRAM which is called as Z-TCAM, because even though the TCAM table provides lookup of entire table in single clock it has various disadvantages when compared to SRAM. TCAM cells, comparator's circuitry in add complexity to the TCAM architecture. The access time of TCAM, is 3.3 times longer than the SRAM access time due to the massive

parallelism [5]. Complex integration of memory and logic also makes TCAM testing very time consuming [3]. The cost of TCAM is also about 30 times more per bit of storage than SRAM [6]. But, the parameters such as area, delay and power can be further reduced by using STT RAM instead of SRAM [1] which has been proved in this work.

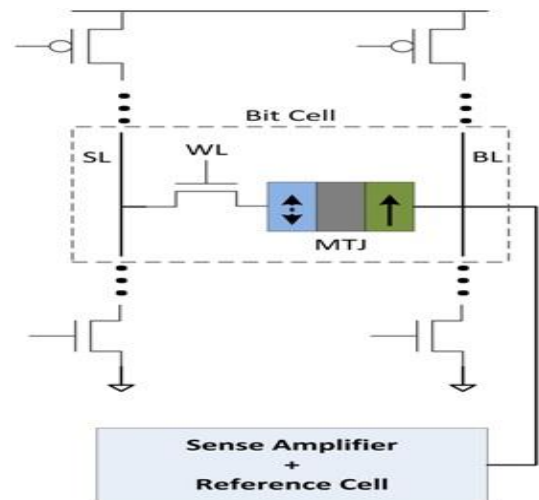


Fig 1: Circuit diagram of STT RAM

Spin transfer torque random access memory (STT-RAM) is an emerging memory technology that promises to deliver the benefits of current non-volatile memories (speed, high density) with the added benefit of being non-volatile and offering no leakage power from the storage element. The detailed architecture and its implementation were explained in the below sections. Critical implementation techniques in low power VLSI design have been discussed in [21], [22] and [23].

Table 1. Traditional TCAM table and its hybrid parameters

ADDR	SW1	SW2	Layer
0	00	11	1
1	01 HP11	01 HP12	
2	0x	11	2
3	11 HP21	1X HP22	

Table 2. Z-TCAM example: Data Mapping

ADD	0	1	2	3
VM11	1	1	0	0
VM12	0	1	0	1
VM21	1	1	0	1
VM22	0	0	1	1
OATAM11	0	0	-	-
OATAM12	-	0	-	1
OATAM21	0	1	-	2
OATAM22	-	-	0	1

Table 3. Z-TCAM Original Address Mapping

ADDR	OAT11	OAT12	OAT21	OAT22
	01	01	23	23
0	10	01	10	01
1	01	10	10	11
2	00	00	01	00
3	00	00	00	00

2. HYBRID PARTITIONING OF TCAM

Hybrid partitioning (HP) is the combination of vertical partitioning and horizontal partitioning of the conventional TCAM table. An example of HP is given in Table 1[1]. HP partitions conventional TCAM table vertically (column wise) and horizontally (row wise) into TCAM sub tables, which are then processed to be stored in their corresponding memory units. This processing (data mapping) has been explained in Section 4.1 with an example (Table 2) to demonstrate the layer architecture of Z-TCAM. Vertical partitioning (VP) implies that a TCAM word of C bits is partitioned into N subwords; each subword is of w bits. The use of VP is to decrease memory size as much as possible. Horizontal partitioning (HrP) divides each vertical partition using the original address range of conventional TCAM table into L horizontal partitions. HrP cannot be used alone as it is area, power, and cost hungry but is used to create layers. HP results in a total of $L \times N$ hybrid partitions.

The dimensions of each hybrid partition are $K \times w$ where K is a subset from original addresses and w is the number of bits in a sub word. Hybrid partitions spanning the same addresses are in the same layer. For example, HP21 and HP22 span the same address range and are in layer 2.

3. ARCHITECTURE OF Z-TCAM

3.1 Overall Architecture

The overall architecture of Z-TCAM is depicted in Fig. 2 where each layer represents the architecture shown in Fig.3. It has L layers and a CAM priority encoder (CPE). Each layer outputs a

potential match address (PMA). The PMAs are fed to CPE, which selects match address (MA) among PMAs.

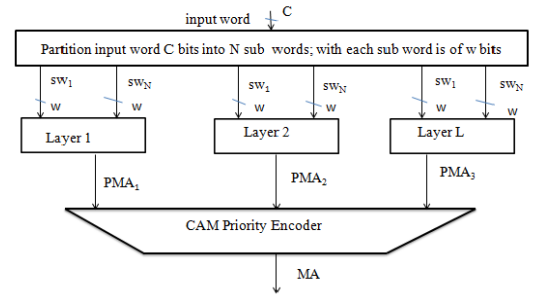


Fig 2: Architecture of Z-TCAM. (sw: subword, C: # of bits in the input word, PMA: potential match address, and MA: match address).

3.2 Layer Architecture

This paper briefs the design with two layers: Layer 1 and Layer 2. Layer architecture is shown in Fig. 3. It contains 2 validation memories (VMs), 1-bit AND operation, 2 original address table address memories (OATAMs), 2 original address tables (OATs), K -bit AND operation, and a layer priority encoder (LPE).

3.2.1 Validation Memory

Size of each VM is $2w \times 1$ bits where w represents the number of bits in each sub word and $2w$ shows the number of rows. A sub word of w bits implies that it has total combinations of 2^w where each combination represents a sub word. For example, if w is of 4 bits, then it means that there are total of $2^4 = 16$ combinations. This explanation is also related to OATAM and OAT. Each sub word acts as an address to VM. If the memory location be invoked by a sub word is high, it means that the input sub word is present, otherwise absent.

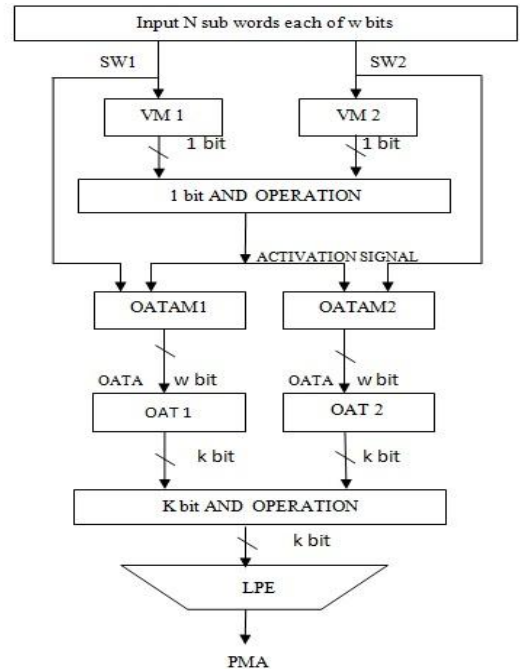


Fig 3: Architecture of a layer of Z-TCAM. (sw: subword, VM: validation memory, OATAM: original address table address memory, OAT: original address table, and LPE: layer priority encoder).

Thus, VM validates the input sub word, if it is present. In Tabel 2 VM 11 , VM 12 belongs to Layer 1 and VM 21 , VM 22 belongs to Layer 2. For example, Table 2 shows that sub words 00 and 01 are mapped in VM 11 , sub words 01 and 11 are mapped to VM 12,etc.This states that memory locations 00 and 01 should be high in VM11 and the remaining memory locations are set to low because their corresponding sub words do not exist.

3.2.2 1-bit AND Operation

It ANDs the output of all VMs. The output of 1-bit AND operation decides the continuation of a search operation. If the result of 1-bit AND operation is high, then it permits the continuation of a search operation, otherwise mismatch occurs in the corresponding layer.

3.2.3 Original Address Table Address Memory

Each OATAM is of $2w \times w$ bits where $2w$ is the number of rows and each row has w bits. In OATAM, an address is stored at the memory location indexed by a subword and that address is then used to invoke a row from its corresponding OAT. If a subword in VM is mapped, then a corresponding address is also stored in OATAM at a memory location accessed by the sub word. For example, Table II shows OATAM21 where addresses are stored at the memory locations 00, 01, and 11. The output of OATAM is called as OATA. Hyphen “-” indicates that the corresponding memory location has no data because the corresponding sub word for the memory location is not present in VM.STTRAM is used to realize OATAM and OAT.

3.2.4 Original Address Table

Dimensions of OAT are $2w \times K$ where w is the number of bits in a subword, $2w$ represents number of rows, and K is the number of bits in each row where each bit represents an original address. Here K is a subset of original addresses from conventional TCAM table. It is OAT, which considers the storage of original addresses. An example of OAT is given in Table III, where 1 shows the presence of a subword at an original address.

3.2.5 K-bit AND Operation

It ANDs bit-by-bit the read out K-bit rows from all OATs and forwards the result to LPE.

3.2.6 Layer Priority Encoder

Because we emulate TCAM and multiple matches may occur in TCAM [17], the LPE selects PMA among the outputs of K-bit AND operation.

4. Z-TCAM OPERATIONS

4.1 Data Mapping Operation

Classical TCAM table is logically partitioned into hybrid partitions. Each hybrid partition is then expanded into a binary version. Thus, we first expand x into states 0 and 1 to be stored in SRAM. For example, if we have a TCAM word of 010 x , then it is expanded into 0100 and 0101. Each subword, acting as an address, is applied to its corresponding VM and a logic “1” is written at that memory location. The same subword is also applied to its respective OATAM and w bits data are written at that memory location. During search, these w bits data act as an address to the OAT. The K bits data are also written at the memory location in OAT determined by its corresponding OATA. Thus, in this way, all hybrid partitions are mapped.

A subword in a hybrid partition can be present at multiple locations. So, it is mapped in its corresponding VM and its original address is/are mapped to its/their corresponding bit(s) in its respective OAT. Since a single bit in OAT represents an original address, only those memory locations in VMs and address positions/ original addresses in OATs are high, which are mapped

while remaining memory locations and address positions are set to low in VMs and OATs, respectively.

Example of data mapping is shown in Table 2. We use Table 1 to be mapped to Z-TCAM. We take $N = 2$, $L = 2$, $K = 2$, and $w = 2$. After necessary processing, HP11, HP12, HP21, and HP22 are mapped to their corresponding memory units. In the example, we map hybrid partitions of layer 2 to their corresponding memory units. Hybrid partitions of layer 1 can be easily mapped in similar way.

Algorithm 1: Pseudo code for searching in a layer of Z-TCAM

```

INPUT : N sub-words
OUTPUT : PMA
1: → Apply N sub-words
2: → Apply all sub-words simultaneously to their VMs
3: → Read all VMs concurrently
4: if all VMs validate their corresponding sub-words then
5: → Sustain search operation
6: → a. Read all OATAMs in parallel
7: → b. Read all OATs simultaneously
8: → c. AND bitwise all K –bits rows
9: → d. Select PMA/mismatch occurs
10: else
11: → Mismatch occurs
12: end if
    
```

Algorithm 2: Pseudo code for searching in Z-TCAM

```

INPUT : Search Key
OUTPUT : MA
1: → Apply search key
2: → Divide search key into N sub word
3: → All layers use algorithm1 in parallel
4: → Select MA among PMAs/mismatch
    Occurs.
    
```

Table 4.Example of a Search Operation in Layer 2 of Z-TCAM

STEPS	ACTIVITY
1	Sub – word 1 = 00 Sub – word2 = 11
2	Sub – word1 is applied to VM21 Sub – word1 is applied to VM22
3	Read out bit from VM21 = 1 Read out bit from VM22 = 1

4	Have all VMs validated their corresponding sub – words?
5	Yes ,so sustain search operation
6	Read out data from OATAM21 = 0 Read out data from OATAM22 = 1
7	Read out data from OAT21 = 10 Read out data from OAT22 = 11
8	K – Bit AND operation result = 10
9	PMA = 2

4.2 Search Operation

4.2.1 Searching in a Layer of Z-TCAM

Algorithm 1 describes searching in a layer of Z-TCAM. N subwords are concurrently applied to a layer. The subwords then read out their corresponding memory locations from their respective VMs. If all VMs validate their corresponding sub words (equivalent to 1-bit AND operation in Fig. 2), then searching will continue, otherwise mismatch occurs in the layer. Upon validation of all subwords, the sub words read out their respective memory locations from their corresponding OATAMs concurrently and output their corresponding OATAs. All OATAs then read out K -bit rows from their corresponding OATs simultaneously, which are then bitwise ANDed. LPE selects PMA from the result of the K -bit AND operation. Example of a search operation in layer 2 is shown in Table 4, following Algorithm 1. Memory blocks in Table 2 need to be searched.

4.2.2 Searching in Z-TCAM

Search operation in the proposed TCAM occurs concurrently in all layers, which follows Algorithm 2. Search key is applied to Z-TCAM, which is then divided into N subwords. After searching, PMAs are available from all layers. CPE selects MA among PMAs; otherwise a mismatch of the input word occurs. Table 5 provides overall search operation in Z-TCAM, which follows Algorithm 2.[1]

Table 5. Example of a Search Operation in Z-TCAM

STEPS	ACTIVITY
1	Search key =0011
2	Sub word 1:=00 Sub word 2=11
3	PMA1=0 PMA2=1
4	CAM Priority Encoder Selects address 0 as MA

5. Z-TCAM IMPLEMENTATION AND RESULTS

5.1 Power Analysis

The power analysis has been done in modelsim for STTAM based Z-TCAM and the obtained output is shown in fig4.

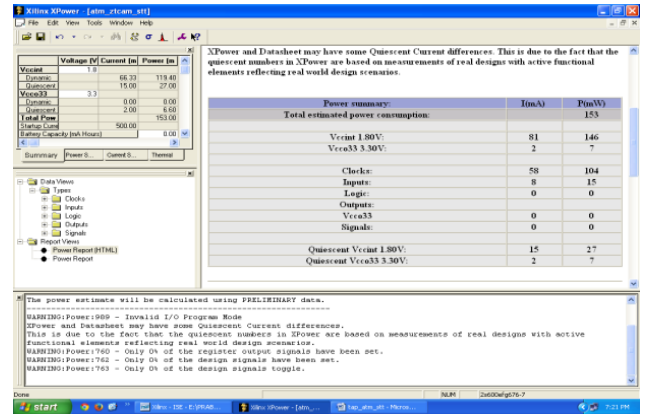


Fig 4: Power Analysis of STTAM based Z-TCAM

5.2 Delay Analysis

The delay analysis has been done in modelsim for STTAM based Z-TCAM and the obtained output is shown in fig5.

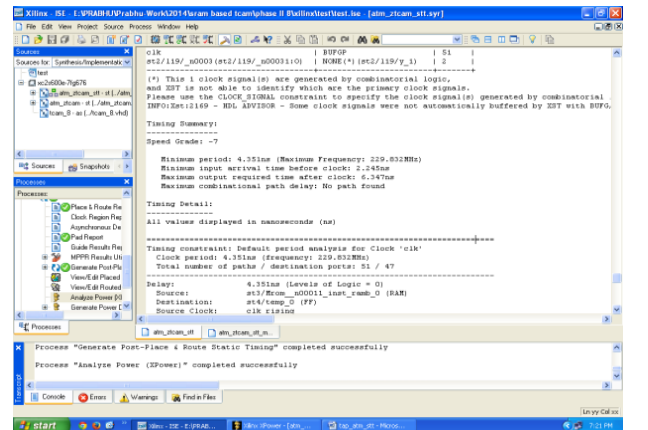


Fig 5: Delay Analysis of STTAM based Z-TCAM

5.3 Area Analysis

The area analysis has been done in modelsim for STTAM based Z-TCAM and the obtained output is shown in fig6.

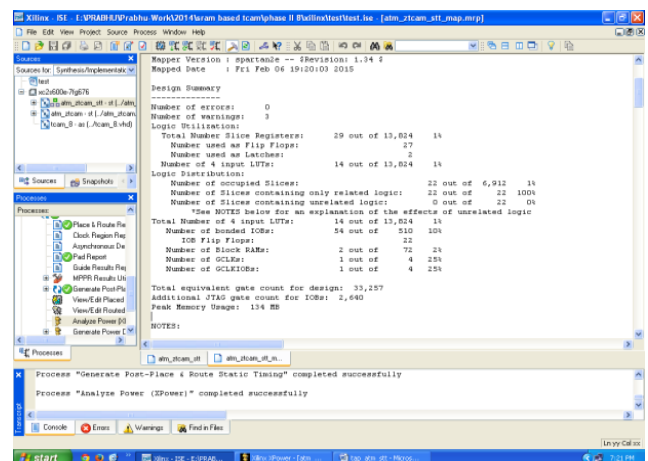


Fig 6: Delay Analysis of STTAM based Z-TCAM.

From fig 7 and 8 it is evident that the area of Z-TCAM architecture is optimized by using STT RAM in place of SRAM. The optimized area places a vital role in VLSI circuit design.

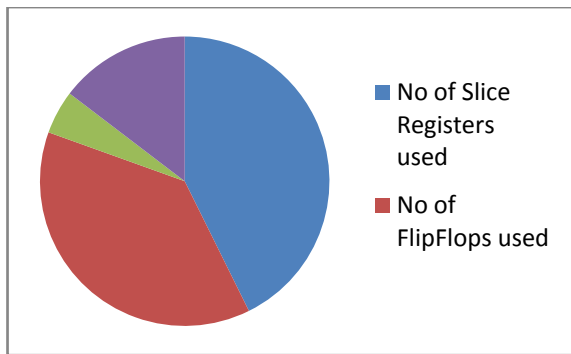


Fig 7: Area of SRAM based Z-TCAM

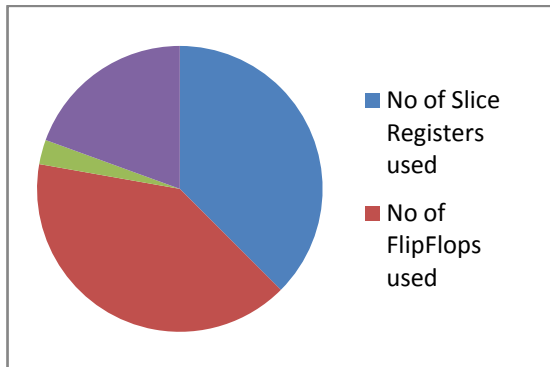


Fig 8: Area of STT RAM based Z-TCAM

Table 6. Comparison table of SRAM and STTRAM based ZTCAM

PARAMETERS	SRAM BASED Z-TCAM	STT RAM BASED Z-TCAM
POWER(mW)	163	153
DELAY(ns)	4.711	4.351
NO OF GATES USED	33,319	33,257

From table 6 it is clear that the power, delay and area is optimized by using STT RAM instead of SRAM which is highly significant in VLSI based circuits.

6. CONCLUSION

In brief this paper presents a novel STT RAM-based TCAM architecture of Z-TCAM with optimized area, power and delay parameters. Moreover, the proposed TCAM has a simpler structure, and very importantly, has a deterministic search performance of one word comparison per clock cycle. It is a solution for fastest memory searches, so it can be used in high speed search intensive applications such as Network switch, ATM Switch, IP Filter.

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